

TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

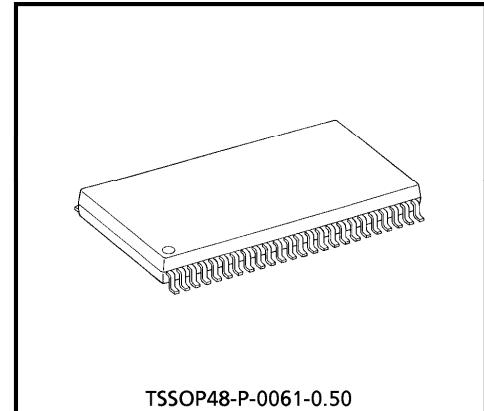
**TC74VCX16244FT****LOW-VOLTAGE 16-BIT BUS BUFFER  
WITH 3.6V TOLERANT INPUTS AND OUTPUTS**

The TC74VCX16244FT is a high performance CMOS 16-bit BUS BUFFER. Designed for use in 1.8, 2.5 or 3.3 Volt systems, it achieves high speed operation while maintaining the CMOS low power dissipation.

It is also designed with over voltage tolerant inputs and outputs up to 3.6V.

This device is non-inverting 3-state buffer having four active-low output enables. It can be used as four 4-bit buffers two 8-bit buffers or one 16-bit buffer. When the  $\overline{OE}$  input is high, the outputs are in a high impedance state. This device is designed to be used with 3-state memory address drivers, etc.

All inputs are equipped with protection circuits against static discharge.



TSSOP48-P-0061-0.50

Weight : 0.25g (Typ.)

**FEATURES**

- Low Voltage Operation :  $V_{CC} = 1.8 \sim 3.6V$
- High Speed Operation :  $t_{pd} = 2.5ns$  (max.) at  $V_{CC} = 3.0 \sim 3.6V$   
:  $t_{pd} = 3.2ns$  (max.) at  $V_{CC} = 2.3 \sim 2.7V$   
:  $t_{pd} = 5.7ns$  (max.) at  $V_{CC} = 1.8V$
- 3.6V Tolerant inputs and outputs.
- Output Current :  $I_{OH}/I_{OL} = \pm 24mA$  (min.) at  $V_{CC} = 3.0V$   
:  $I_{OH}/I_{OL} = \pm 18mA$  (min.) at  $V_{CC} = 2.3V$   
:  $I_{OH}/I_{OL} = \pm 6mA$  (min.) at  $V_{CC} = 1.8V$
- Latch-up Performance :  $\pm 300mA$
- ESD Performance : Human Body Model  $> \pm 2000V$   
: Machine Model  $> \pm 200V$
- Package : TSSOP  
(Thin Shrink Small Outline Package)
- Power Down Protection is provided on all inputs and outputs.
- Supports live insertion / withdrawal (Note 1)

(Note 1) To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

**PIN CONNECTION**

$\overline{OE}$	1	48	$\overline{OE}$
Y1	2	47	1A1
Y2	3	46	1A2
GND	4	45	GND
Y3	5	44	1A3
Y4	6	43	1A4
$V_{CC}$	7	42	$V_{CC}$
Y1	8	41	2A1
Y2	9	40	2A2
GND	10	39	GND
Y3	11	38	2A3
Y4	12	37	2A4
Y1	13	36	3A1
Y2	14	35	3A2
GND	15	34	GND
Y3	16	33	3A3
Y4	17	32	3A4
$V_{CC}$	18	31	$V_{CC}$
Y1	19	30	4A1
Y2	20	29	4A2
GND	21	28	GND
Y3	22	27	4A3
Y4	23	26	4A4
$4OE$	24	25	$3OE$

(TOP VIEW)

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## TRUTH TABLE

INPUTS		OUTPUTS
$\bar{OE}$	1A1-1A4	1Y1-1Y4
L	L	L
L	H	H
H	X	Z

INPUTS		OUTPUTS
$2\bar{OE}$	1A1-2A4	2Y1-2Y4
L	L	L
L	H	H
H	X	Z

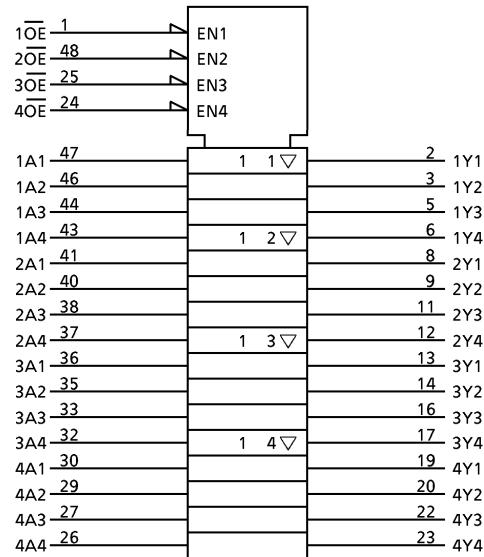
INPUTS		OUTPUTS
$3\bar{OE}$	3A1-3A4	3Y1-3Y4
L	L	L
L	H	H
H	X	Z

INPUTS		OUTPUTS
$4\bar{OE}$	4A1-4A4	4Y1-4Y4
L	L	L
L	H	H
H	X	Z

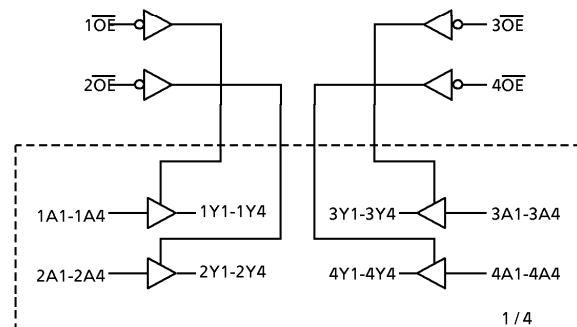
X : Don't Care

Z : High impedance

## IEC LOGIC SYMBOL



## SYSTEM DIAGRAM



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## MAXIMUM RATINGS

PARAMETER	SYMBOL	RATING	UNIT
Power Supply Voltage	$V_{CC}$	-0.5~4.6	V
DC Input Voltage	$V_{IN}$	-0.5~4.6	V
DC Output Voltage	$V_{OUT}$	-0.5~4.6 (Note 1)	V
		-0.5~ $V_{CC}$ +0.5 (Note 2)	
Input Diode Current	$I_{IK}$	-50	mA
Output Diode Current	$I_{OK}$	$\pm 50$ (Note 3)	mA
DC Output Current	$I_{OUT}$	$\pm 50$	mA
Power Dissipation	$P_D$	400	mW
DC $V_{CC}$ / Ground Current Per Supply Pin	$I_{CC} / I_{GND}$	$\pm 100$	mA
Storage Temperature	$T_{stg}$	-65~150	°C

(Note 1) Off-State

(Note 2) High or Low State.  $I_{OUT}$  absolute maximum rating must be observed.(Note 3)  $V_{OUT} < GND$ ,  $V_{OUT} > V_{CC}$ 

## RECOMMENDED OPERATING RANGE

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	$V_{CC}$	1.8~3.6	V
		1.2~3.6 (Note 4)	
Input Voltage	$V_{IN}$	-0.3~3.6	V
Output Voltage	$V_{OUT}$	0~3.6 (Note 5)	V
		0~ $V_{CC}$ (Note 6)	
Output Current	$I_{OH} / I_{OL}$	$\pm 24$ (Note 7)	mA
		$\pm 18$ (Note 8)	
		$\pm 6$ (Note 9)	
Operating Temperature	$T_{opr}$	-40~85	°C
Input Rise And Fall Time	$dt / dv$	0~10 (Note 10)	ns/V

(Note 4) Data Retention Only

(Note 5) Off-State

(Note 6) High or Low State

(Note 7)  $V_{CC} = 3.0 \sim 3.6V$ (Note 8)  $V_{CC} = 2.3 \sim 2.7V$ (Note 9)  $V_{CC} = 1.8V$ (Note 10)  $V_{IN} = 0.8 \sim 2.0V$ ,  $V_{CC} = 3.0V$

**ELECTRICAL CHARACTERISTICS**DC characteristics ( $T_a = -40\sim85^\circ C$ ,  $2.7V < V_{CC} \leq 3.6V$ )

PARAMETER		SYMBOL	TEST CONDITION		$V_{CC}$ (V)	MIN.	MAX.	UNIT	
Input Voltage	"H" Level	$V_{IH}$			2.7~3.6	2.0	—	V	
	"L" Level	$V_{IL}$			2.7~3.6	—	0.8	V	
Output Voltage	"H" Level	$V_{OH}$	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OH} = -100\mu A$	2.7~3.6	$V_{CC} - 0.2$	—	V	
				$I_{OH} = -12mA$	2.7	2.2	—		
				$I_{OH} = -18mA$	3.0	2.4	—		
				$I_{OH} = -24mA$	3.0	2.2	—		
	"L" Level	$V_{OL}$	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OL} = 100\mu A$	2.7~3.6	—	0.2	V	
				$I_{OL} = 12mA$	2.7	—	0.4		
				$I_{OL} = 18mA$	3.0	—	0.4		
				$I_{OL} = 24mA$	3.0	—	0.55		
Input Leakage Current	$I_{IN}$	$V_{IN} = 0\sim 3.6V$		2.7~3.6	—	$\pm 5.0$	$\mu A$		
3-State Output Off-State Current	$I_{OZ}$	$V_{IN} = V_{IH}$ or $V_{IL}$ $V_{OUT} = 0\sim 3.6V$		2.7~3.6	—	$\pm 10.0$	$\mu A$		
Power Off Leakage Current	$I_{OFF}$	$V_{IN}, V_{OUT} = 0\sim 3.6V$		0	—	10.0	$\mu A$		
Quiescent Supply Current		$I_{CC}$	$V_{IN} = V_{CC}$ or GND	2.7~3.6	—	20.0	$\mu A$		
			$V_{CC} \leq (V_{IN}, V_{OUT}) \leq 3.6V$	2.7~3.6	—	$\pm 20.0$			
Increase In $I_{CC}$ Per Input	$\Delta I_{CC}$	$V_{IH} = V_{CC} - 0.6V$		2.7~3.6	—	750	$\mu A$		

**ELECTRICAL CHARACTERISTICS**DC characteristics ( $T_a = -40\sim85^\circ C$ ,  $2.3V \leq V_{CC} \leq 2.7V$ )

PARAMETER		SYMBOL	TEST CONDITION		$V_{CC}$ (V)	MIN.	MAX.	UNIT
Input Voltage	"H" Level		$V_{IH}$	2.3~2.7				
	"L" Level	$V_{IL}$		2.3~2.7	—	0.7	V	
Output Voltage	"H" Level	$V_{OH}$	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OH} = -100\mu A$	2.3~2.7	$V_{CC} - 0.2$	—	V
				$I_{OH} = -6mA$	2.3	2.0	—	
				$I_{OH} = -12mA$	2.3	1.8	—	
				$I_{OH} = -18mA$	2.3	1.7	—	
	"L" Level	$V_{OL}$	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OL} = 100\mu A$	2.3~2.7	—	0.2	V
				$I_{OL} = 12mA$	2.3	—	0.4	
				$I_{OL} = 18mA$	2.3	—	0.6	
Input Leakage Current	$I_{IN}$		$V_{IN} = 0\sim 3.6V$	2.3~2.7	—	$\pm 5.0$	$\mu A$	
3-State Output Off-State Current	$I_{OZ}$		$V_{IN} = V_{IH}$ or $V_{IL}$ $V_{OUT} = 0\sim 3.6V$	2.3~2.7	—	$\pm 10.0$	$\mu A$	
Power Off Leakage Current	$I_{OFF}$		$V_{IN}, V_{OUT} = 0\sim 3.6V$	0	—	10.0	$\mu A$	
Quiescent Supply Current	$I_{CC}$		$V_{IN} = V_{CC}$ or GND	2.3~2.7	—	20.0	$\mu A$	
			$V_{CC} \leq (V_{IN}, V_{OUT}) \leq 3.6V_{CC}$	2.3~2.7	—	$\pm 20.0$		

**ELECTRICAL CHARACTERISTICS**DC characteristics ( $T_a = -40 \sim 85^\circ C$ ,  $1.8V \leq V_{CC} < 2.3V$ )

PARAMETER		SYMBOL	TEST CONDITION		$V_{CC}$ (V)	MIN.	MAX.	UNIT		
Input Voltage	"H" Level	$V_{IH}$				1.8~2.3	$0.7 \times V_{CC}$	—	V	
	"L" Level	$V_{IL}$				1.8~2.3	—	$0.2 \times V_{CC}$	V	
Output Voltage	"H" Level	$V_{OH}$	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OH} = -100\mu A$ $I_{OH} = -6mA$	1.8	$V_{CC} - 0.2$	—	V		
	"L" Level	$V_{OL}$	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OL} = 100\mu A$ $I_{OL} = 6mA$	1.8	1.4	—	V		
Input Leakage Current	$I_{IN}$	$V_{IN} = 0 \sim 3.6V$			1.8	—	$\pm 5.0$	$\mu A$		
3-State Output Off-State Current	$I_{OZ}$	$V_{IN} = V_{IH}$ or $V_{IL}$ $V_{OUT} = 0 \sim 3.6V$			1.8	—	$\pm 10.0$	$\mu A$		
Power Off Leakage Current	$I_{OFF}$	$V_{IN}, V_{OUT} = 0 \sim 3.6V$			0	—	10.0	$\mu A$		
Quiescent Supply Current	$I_{CC}$	$V_{IN} = V_{CC}$ or GND			1.8	—	20.0	$\mu A$		
		$V_{CC} \leq (V_{IN}, V_{OUT}) \leq 3.6V$			1.8	—	$\pm 20.0$			

AC characteristics ( $T_a = -40 \sim 85^\circ C$ , Input  $t_r = t_f = 2.0\text{ns}$ ,  $C_L = 30\text{pF}$ ,  $R_L = 500\Omega$ )

PARAMETER		SYMBOL	TEST CONDITION		$V_{CC}$ (V)	MIN.	MAX.	UNIT		
Propagation Delay Time		$t_{pLH}$ $t_{pHL}$	(Fig.1, 2)			1.8	1.5	5.0	ns	
						$2.5 \pm 0.2$	1.0	3.0		
						$3.3 \pm 0.3$	0.8	2.5		
3-State Output Enable Time		$t_{pzL}$ $t_{pzH}$	(Fig.1, 3)			1.8	1.5	6.5	ns	
						$2.5 \pm 0.2$	1.0	4.1		
						$3.3 \pm 0.3$	0.8	3.5		
3-State Output Disable Time		$t_{pLZ}$ $t_{pHZ}$	(Fig.1, 3)			1.8	1.5	5.0	ns	
						$2.5 \pm 0.2$	1.0	3.8		
						$3.3 \pm 0.3$	0.8	3.5		
Output To Output Skew		$t_{osLH}$ $t_{osHL}$	(Note 11)			1.8	—	0.5	ns	
						$2.5 \pm 0.2$	—	0.5		
						$3.3 \pm 0.3$	—	0.5		

For  $C_L = 50\text{pF}$ , add approximately 300ps to the AC maximum specification.

(Note 11) Parameter guaranteed by design.  
 $(t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|)$

Dynamic switching characteristics ( $T_a = 25^\circ\text{C}$ , Input  $t_r = t_f = 2.0\text{ns}$ ,  $C_L = 30\text{pF}$ )

PARAMETER	SYMBOL	TEST CONDITION	$V_{CC} (\text{V})$	TYP.	UNIT
Quiet Output Maximum Dynamic $V_{OL}$	$V_{OLP}$	$V_{IH} = 1.8\text{V}, V_{IL} = 0\text{V}$ (Note 12)	1.8	0.25	V
		$V_{IH} = 2.5\text{V}, V_{IL} = 0\text{V}$ (Note 12)	2.5	0.6	
		$V_{IH} = 3.3\text{V}, V_{IL} = 0\text{V}$ (Note 12)	3.3	0.8	
Quiet Output Minimum Dynamic $V_{OL}$	$V_{OLV}$	$V_{IH} = 1.8\text{V}, V_{IL} = 0\text{V}$ (Note 12)	1.8	-0.25	V
		$V_{IH} = 2.5\text{V}, V_{IL} = 0\text{V}$ (Note 12)	2.5	-0.6	
		$V_{IH} = 3.3\text{V}, V_{IL} = 0\text{V}$ (Note 12)	3.3	-0.8	
Quiet Output Minimum Dynamic $V_{OH}$	$V_{OHV}$	$V_{IH} = 1.8\text{V}, V_{IL} = 0\text{V}$ (Note 12)	1.8	1.5	V
		$V_{IH} = 2.5\text{V}, V_{IL} = 0\text{V}$ (Note 12)	2.5	1.9	
		$V_{IH} = 3.3\text{V}, V_{IL} = 0\text{V}$ (Note 12)	3.3	2.2	

(Note 12) Parameter guaranteed by design.

Capacitive characteristics ( $T_a = 25^\circ\text{C}$ )

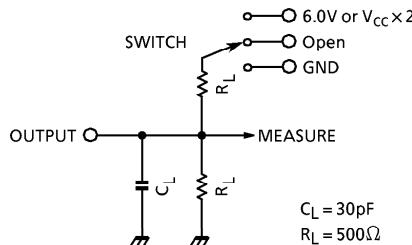
PARAMETER	SYMBOL	TEST CONDITION	$V_{CC} (\text{V})$	TYP.	UNIT
Input Capacitance	$C_{IN}$		1.8, 2.5, 3.3	6	pF
Output Capacitance	$C_O$		1.8, 2.5, 3.3	7	pF
Power Dissipation Capacitance	$C_{PD}$	$f_{IN} = 10\text{MHz}$ (Note 13)	1.8, 2.5, 3.3	20	pF

(Note 13)  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation :

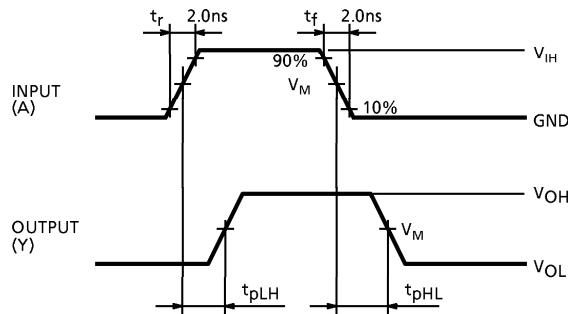
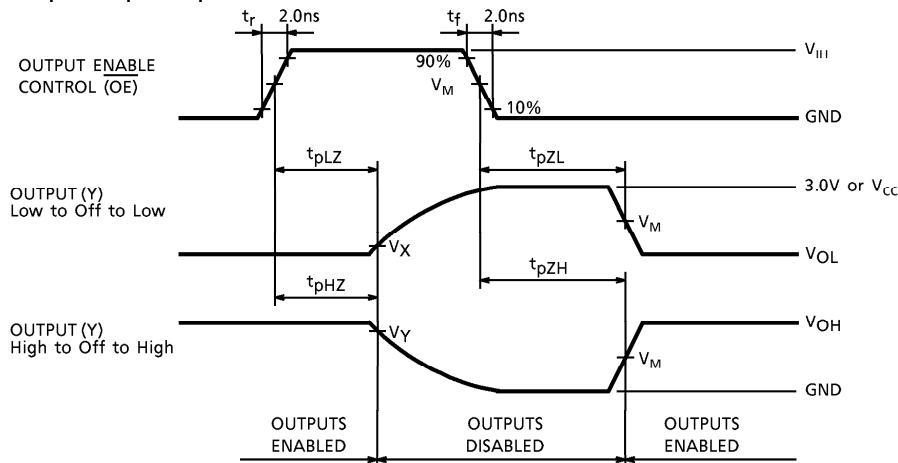
$$I_{CC}(\text{opr.}) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 16 \text{ (per bit)}$$

Fig.1 Test circuit



PARAMETER	SWITCH
$t_{pLH}, t_{pHL}$	Open
$t_{pLZ}, t_{pZL}$	6.0V @ $V_{CC} = 3.3 \pm 0.3\text{V}$ $V_{CC}x2$ @ $V_{CC} = 2.5 \pm 0.2\text{V}$ @ $V_{CC} = 1.8\text{V}$
$t_{pHZ}, t_{pZH}$	GND

## AC WAVEFORM

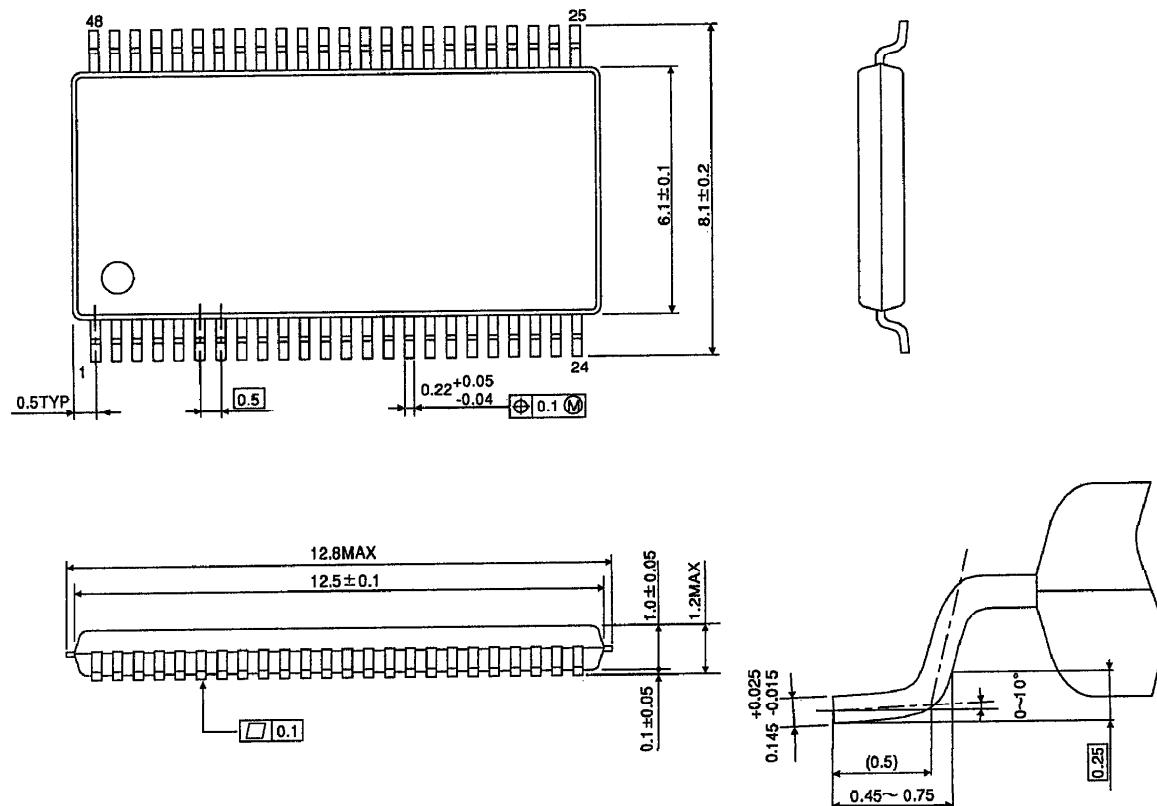
Fig.2  $t_{pLH}, t_{pHL}$ Fig.3  $t_{pLZ}, t_{pHZ}, t_{pZL}, t_{pZH}$ 

SYMBOL	$V_{CC}$		
	$3.3 \pm 0.3\text{V}$	$2.5 \pm 0.2\text{V}$	$1.8\text{V}$
$V_{IH}$	2.7V	$V_{CC}$	$V_{CC}$
$V_M$	1.5V	$V_{CC}/2$	$V_{CC}/2$
$V_X$	$V_{OL} + 0.3\text{V}$	$V_{OL} + 0.15\text{V}$	$V_{OL} + 0.15\text{V}$
$V_Y$	$V_{OH} - 0.3\text{V}$	$V_{OH} - 0.15\text{V}$	$V_{OH} - 0.15\text{V}$

## OUTLINE DRAWING

TSSOP48-P-0061-0.50

Unit : mm



Weight : 0.25g (Typ.)